

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	-20	V		
Gate-Source Voltage			V_{GSS}	±12	V
Continuous Drain Current (Note S) V 4 EV	Steady	T _A = +25°C	I-	-7.0	А
Continuous Drain Current (Note 6) V _{GS} = -4.5V	State	T _A = +70°C	I _D	-5.5	
Continuous Drain Current (Note 7) V _{GS} = -4.5V	Steady State	T _C = +25°C	,	-15	А
		T _C = +70°C	ID	-12	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	-30	Α		
Continuous Source-Drain Diode Current (Note 6)			Is	-2.2	Α
Avalanche Current (Note 8) L = 0.1mH	I _{AS}	-16	Α		
Avalanche Energy (Note 8) L = 0.1mH			E _{AS}	13.5	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	P_{D}	1.4	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	91	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	P _D	1.9	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	64	°C/W
Thermal Resistance, Junction to Case (Note 7)	Steady State	R _{0JC}	13.5	°C/W
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +150	°C

Electrical Characteristics (T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-1	μA	$V_{DS} = -16V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)	ON CHARACTERISTICS (Note 9)						
Gate Threshold Voltage	V _{GS(TH)}	-0.6	_	-1.5	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
Static Drain-Source On-Resistance	D	_	26	33	mΩ	$V_{GS} = -4.5V, I_D = -8.9A$	
Static Diani-Source On-Resistance	R _{DS(ON)}	_	37.5	52		V _{GS} = -2.5V, I _D = -6.9A	
Diode Forward Voltage	V _{SD}	_	-0.7	-1.2	V	V _{GS} = 0V, I _S = -2.9A	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss		834	_		V _{DS} = -10V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	133	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	105	_			
Gate Resistance	Rg	_	4.9	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$	
Total Gate Charge (V _{GS} = -4.5V)	Q_g	_	8.6	_			
Total Gate Charge (V _{GS} = -8V)	Qg	_	19	_	nC	$V_{DS} = -6V, I_{D} = -8.9A$	
Gate-Source Charge	Q _{gs}	_	1.5	_	lic		
Gate-Drain Charge	Q _{gd}	_	2.5	_			
Turn-On Delay Time	t _{D(ON)}	_	5.8	_		V_{DD} = -6V, R_L = 6 Ω V_{GS} = -4.5V, R_g = 6 Ω , I_D = -1A	
Turn-On Rise Time	t _R	_	7.7	_	no		
Turn-Off Delay Time	t _{D(OFF)}	_	28.1	_	ns		
Turn-Off Fall Time	t _F		14.6	_]		
Body Diode Reverse Recovery Time	t _{RR}		9.8	_	ns	I _F = -8.9A, di/dt = -100A/μs	
Body Diode Reverse Recovery Charge	Q_{RR}		2.7	_	nC	$I_F = -8.9A$, $di/dt = -100A/\mu s$	

Notes:

^{5.} Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.7. Thermal resistance from junction to soldering point (on the exposed drain pad).

^{8.} I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.

^{9.} Short duration pulse test used to minimize self-heating effect.

^{10.} Guaranteed by design. Not subject to product testing.





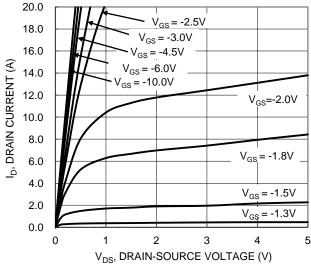
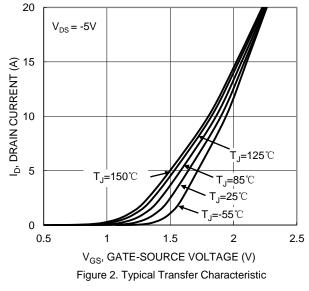


Figure 1. Typical Output Characteristic



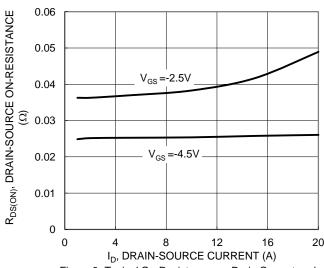


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

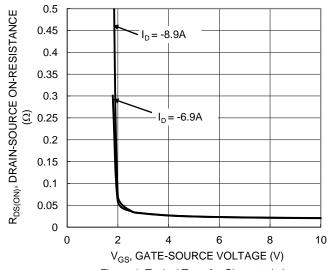


Figure 4. Typical Transfer Characteristic

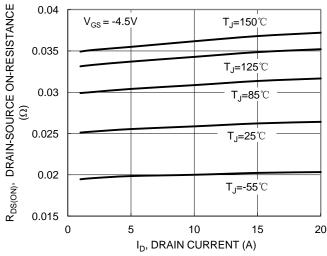


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

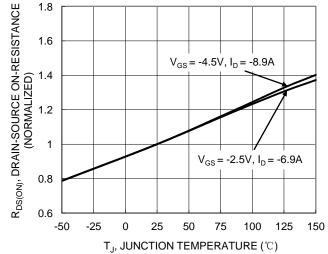


Figure 6. On-Resistance Variation with Junction Temperature



DMP2040USS

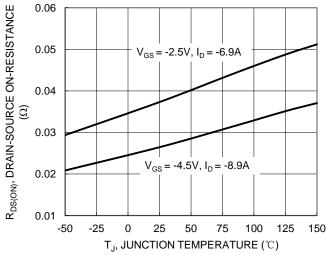


Figure 7. On-Resistance Variation with Junction Temperature

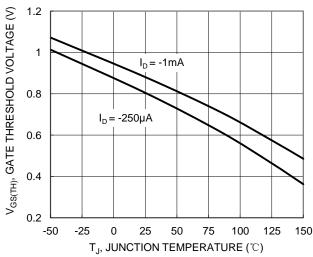


Figure 8. Gate Threshold Variation vs. Junction Temperature

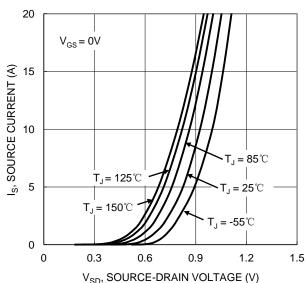
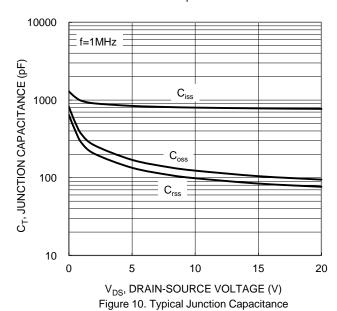
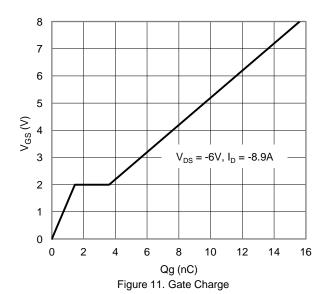


Figure 9. Diode Forward Voltage vs. Current



100 $R_{DS(ON)}$ Limited _v =100µs ID, DRAIN CURRENT (A) 10 1 $P_W = 10ms$ $P_W = 100 ms$ P_W =1s 0.1 $T_{J(Max)} = 150^{\circ}C$ $T_C = 25^{\circ}C$ Single Pulse DUT on 1*MRP Board DC $V_{GS} = -4.5V$ 0.01 0.1 10 V_{DS} , DRAIN-SOURCE VOLTAGE (V) Figure 12. SOA, Safe Operation Area



100



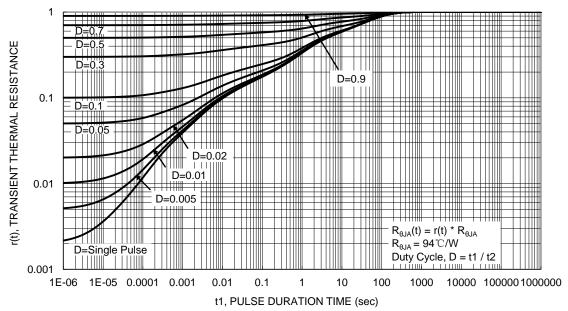


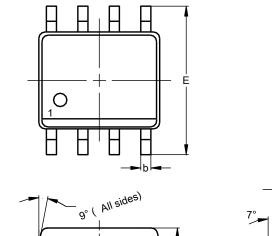
Figure 13. Transient Thermal Resistance

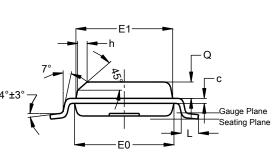


Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8



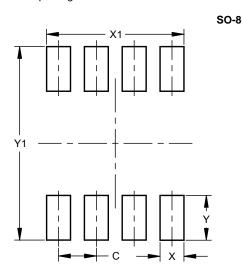


SO-8					
Dim	Min	Max	Тур.		
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
b	0.30	0.50	0.40		
С	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
е	-		1.27		
h			0.35		
L	0.62	0.82	0.72		
Q	0.60	0.70	0.65		
All Dimensions in mm					

Suggested Pad Layout

40.1°

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50



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